74HC4520-Q100; 74HCT4520-Q100

Dual 4-bit synchronous binary counter

Rev. 4 — 2 April 2024

Product data sheet

1. General description

The 74HC4520-Q100; 74HCT4520-Q100 are dual 4-bit internally synchronous binary counters with two clock inputs (nCP0 and n $\overline{CP1}$). They have buffered outputs from all 4 bit positions (nQ0 to nQ3), and an asynchronous master reset input (nMR). The counter advances on either the LOW-to-HIGH transition of nCP0 when n $\overline{CP1}$ is HIGH. It also advances on the HIGH-to-LOW transition of n $\overline{CP1}$ if nCP0 is LOW. Either nCP0 or n $\overline{CP1}$ may be used as the clock input to the counter. The other clock input may be used as a clock enable input. A HIGH on nMR resets the counter (nQ0 to nQ3 = LOW) independent of nCP0 and n $\overline{CP1}$. Inputs include clamp diodes. It enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- Input levels:
 - For 74HC4520-Q100: CMOS level
 - For 74HCT4520-Q100: TTL level
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

3. Applications

- Multistage synchronous counting
- Multistage asynchronous counting
- Frequency dividers

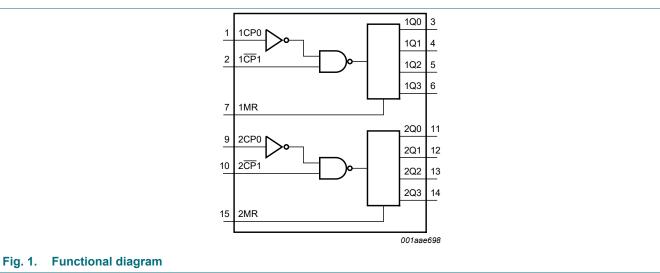


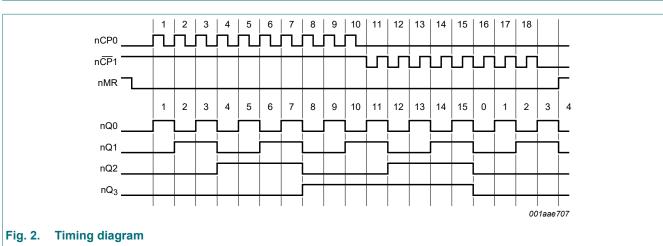
4. Ordering information

Table 1. Ordering information

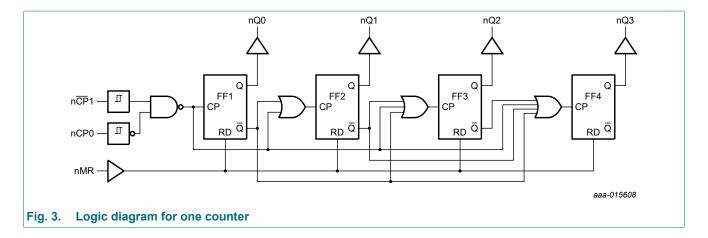
Type number	mber Package										
	Temperature range	Name	Description	Version							
74HC4520D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1							
74HCT4520D-Q100	-		body width 3.9 mm								
74HC4520PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							

5. Functional diagram



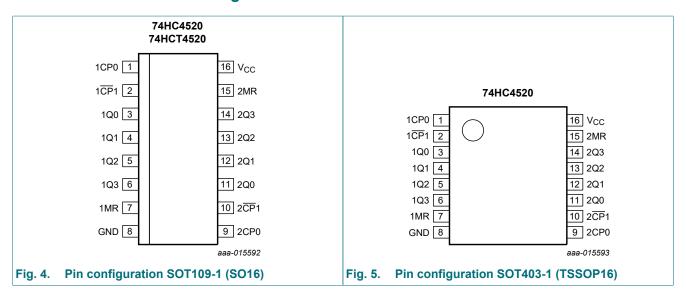


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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1CP0, 2CP0	1, 9	clock input (LOW-to-HIGH edge-triggered)
1CP1, 2CP1	2, 10	clock input (HIGH-to-LOW edge-triggered)
1Q0 to 1Q3	3, 4, 5, 6	output
1MR, 2MR	7, 15	asynchronous master reset input (active HIGH)
GND	8	ground (0 V)
2Q0 to 2Q3	11, 12, 13, 14	output
V _{CC}	16	supply voltage

7. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ \uparrow = positive-going \ transition; \ \downarrow = negative-going \ transition.$

nCP0	nCP1	nMR	Mode
↑	Н	L	counter advances
L	\downarrow	L	counter advances
↓	X	L	no change
X	\uparrow	L	no change
↑	L	L	no change
Н	\downarrow	L	no change
X	X	Н	nQ0 to nQ3 = LOW

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[1]	-	500	mW

^[1] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC4520-Q100		74H	CT4520-0	Q100	Unit	
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
V _O	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC45	20-Q100				•					
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
OL	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80.0	-	160.0	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT4	520-Q100									
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	Ι _O = -20 μΑ	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	Ι _O = 20 μΑ	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80.0	-	160.0	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V ; $I_O = 0 \text{ A}$								
		pin nCP0, nCP1	-	80	288	-	360	-	392	μΑ
		pin nMR	-	150	540	-	675	-	735	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit, see Fig. 8.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
				Тур	Max	Min	Max	Min	Max	
74HC45	20-Q100					•		•		
t _{pd}	propagation	nCP0 to nQn; see Fig. 6 [1]								
	delay	V _{CC} = 2.0 V	-	77	240	-	300	-	360	ns
		V _{CC} = 4.5 V	-	28	48	-	60	-	72	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	22	41	-	51	-	61	ns
		nCP1 to nQn; see Fig. 6 [1]								
		V _{CC} = 2.0 V	-	77	240	-	300	-	360	ns
		V _{CC} = 4.5 V	-	28	48	-	60	-	72	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	22	41	-	51	-	61	ns
t _{PHL}		nMR to nQn; see Fig. 6								
	propagation delay	V _{CC} = 2.0 V	-	44	150	-	190	-	225	ns
	delay	V _{CC} = 4.5 V	-	16	30	-	38	-	45	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	13	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	13	26	-	33	-	38	ns
t _t	transition	nQn; see Fig. 6 [2]								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	1
t _W	pulse width	nCP0, nCP1 HIGH or LOW; see Fig. 7								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		nMR HIGH; see <u>Fig. 7</u>								
		V _{CC} = 2.0 V	120	39	-	150	-	180	-	ns
		V _{CC} = 4.5 V	24	14	-	30	-	36	-	ns
		V _{CC} = 6.0 V	20	11	-	26	-	31	-	ns
t _{rec}	recovery time	nMR to nCP0, nCP1; see Fig. 7								
		V _{CC} = 2.0 V	0	-28	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-10	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-8	-	0	-	0	-	ns
t _{su}	set-up time	nCP0 to nCP1; nCP1 to nCP0; see Fig. 6								
		V _{CC} = 2.0 V	80	14	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	4	-	17	-	20	-	ns
f _{max}	maximum	nCP0, nCP1; see Fig. 7								
	frequency	V _{CC} = 2.0 V	6	19	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V	30	58	_	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	68	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	69	_	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	V_i = GND to V_{CC} ; V_{CC} = 5 V; [3] f_i = 1 MHz	-	29	-	-	-	-	-	pF
74HCT4	520-Q100								l	
t _{pd}	propagation	nCP0 to nQn; see Fig. 6 [1]								
	delay	V _{CC} = 4.5 V	-	28	53	-	66	-	80	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
		nCP1 to nQn; see Fig. 6 [1]								
		V _{CC} = 4.5 V	-	25	53	-	66	-	80	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	24	-	-	-	-	-	ns
t _{PHL}	HIGH to LOW	nMR to nQn; see Fig. 6								
	propagation	V _{CC} = 4.5 V	-	16	35	-	44	-	53	ns
	delay	V _{CC} = 5.0 V; C _L = 15 pF	-	13	_	-	-	-	_	ns
t _t	transition	nQn; see Fig. 6 [2]								+
	time	V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	nCP0, nCP1 HIGH or LOW; see Fig. 7								
		V _{CC} = 4.5 V	20	10	-	25	-	30	-	ns
		nMR HIGH; see <u>Fig. 7</u>								<u> </u>
		V _{CC} = 4.5 V	20	12	_	25	-	30	_	ns

Symbol Parameter		Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C	
			Min	Тур	Max	Min	Max	Min	Max	
t _{rec}	recovery time	nMR to nCP0, nCP1; see Fig. 7								
		V _{CC} = 4.5 V	0	-8	-	0	-	0	-	ns
t _{su}	set-up time	nCP0 to nCP1; nCP1 to nCP0; see Fig. 6								
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
f _{max}	maximum	nCP0, nCP1; see Fig. 7								
	frequency	V _{CC} = 4.5 V	30	58	-	24	-	20	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	64	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}; V_{CC} = 5 \text{ V}; [3]$ $f_i = 1 \text{ MHz}$	-	24	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} . [2] t_t is the same as t_{THL} and t_{TLH} . [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_1 \times V_{CC}^2 \times f_0)$$
 where

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

11.1. Waveforms and test circuit

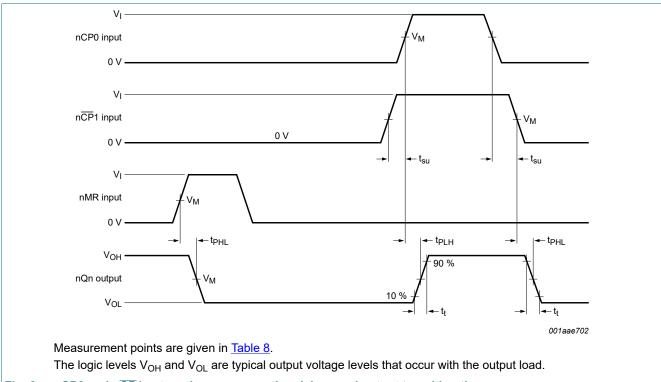


Fig. 6. nCP0 and nCP1 set-up times, propagation delays and output transition times

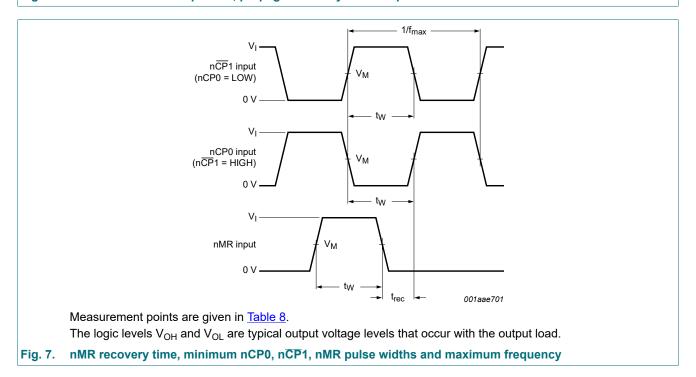
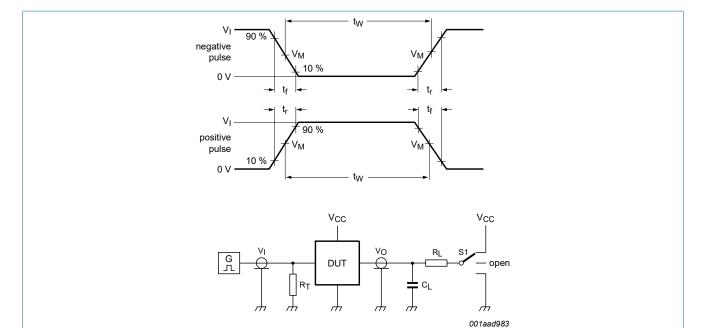


Table 8. Measurement points

Table 6. Measurement points	odduromone pointo								
Туре	Input	Output							
	V_{M}	V _I	V _M						
74HC4520-Q100	0.5 × V _{CC}	GND to V _{CC}	0.5 × V _{CC}						
74HCT4520-Q100	1.3 V	GND to 3 V	1.3 V						



Test data is given in Table 9.

Test circuit definitions:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator

C_L = Load capacitance including jig and probe capacitance

 R_L = Load resistance.

S1 = Test selection switch

Fig. 8. Test circuit for measuring switching times

Table 9. Test data

Туре	Input			Load			oad		
	V _I	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}				
74HC4520-Q100	GND to V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open				
74HCT4520-Q100	GND to 3 V	6 ns	15 pF, 50 pF	1 kΩ	open				

12. Package outline

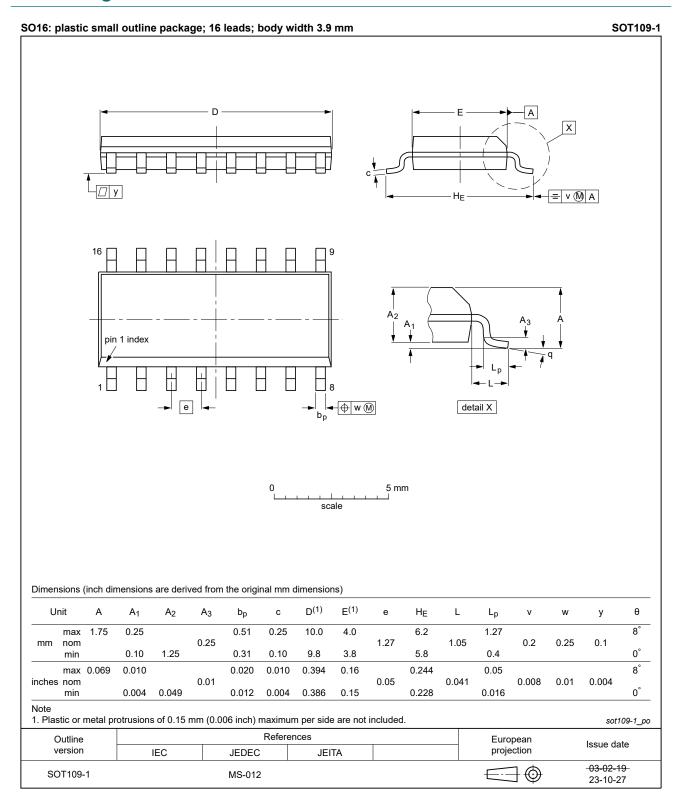


Fig. 9. Package outline SOT109-1 (SO16)

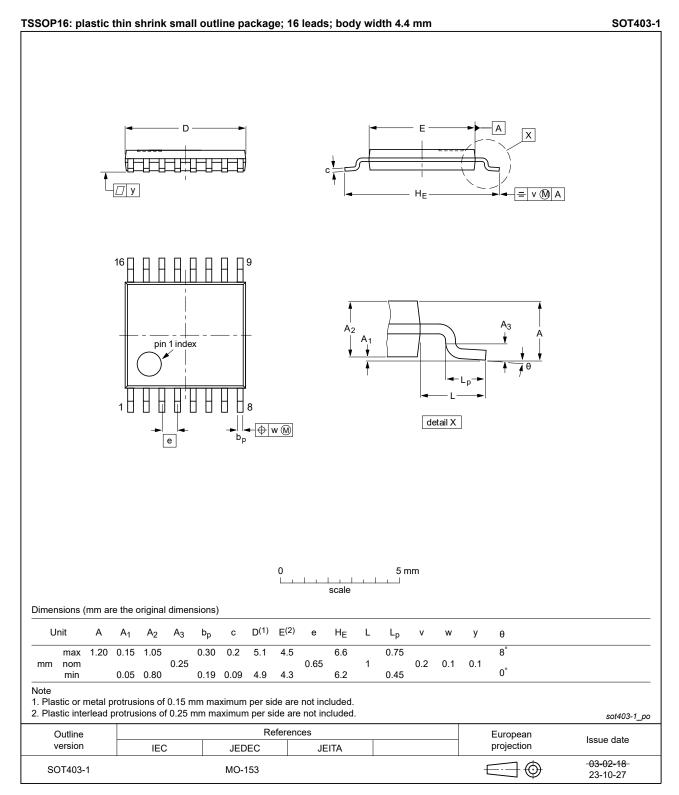


Fig. 10. Package outline SOT403-1 (TSSOP16)

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT4520_Q100 v.4	20240402	Product data sheet	-	74HC_HCT4520_Q100 v.3		
Modifications:	 Fig. 9, Fig. 10: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153. Section 2: ESD specification updated according to the latest JEDEC standard. 					
74HC_HCT4520_Q100 v.3	20201009	Product data sheet	-	74HC_HCT4520_Q100 v.2		
Modifications:	 Type number 74HC4520PW-Q100 (SOT403-1/TSSOP16) added. Section 2 updated. Table 4: Derating values for P_{tot} total power dissipation have been updated. 					
74HC_HCT4520_Q100 v.2	20190214	Product data sheet	-	74HC_HCT4520_Q100 v.1		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74HC4520PW-Q100 (SOT403-1) removed. 					
74HC_HCT4520_Q100 v.1	20141204	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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